The coarsening behavior of duplex Al₂O₃/NiAl₂O₄ composites

W.H. Tuan, M.C. Lin, W.H. Tzing

Institute of Materials Science and Engineering, National Taiwan University, Taipei 10764, Taiwan, ROC

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Abstract

In the present study, the grain growth behavior of Al₂O₃/NiAl₂O₄ composite is compared with that of Al₂O₃ and of NiAl₂O₄. Duplex Al₂O₃/NiAl₂O₄ composite shows strong resistance to coarsening. The activation energy for the grain growth of monolithic Al₂O₃ is the same as that of Al₂O₃ in composite. However, the activation energy for the grain growth of NiAl₂O₄ is changed as NiAl₂O₄ is surrounded by Al₂O₃. The shape of Al₂O₃ grains in composite is also different from that of Al₂O₃ in monolithic alumina. The coarsening of one phase in the composite is thus constrained by the presence of another phase.

Keywords: Duplex composite; Coarsening; Activation energy

1. Introduction

Ceramics exhibit superior hardness, chemical stability and high temperature strength. However, they suffer from poor toughness at room temperature. The application of ceramics under ambient conditions is therefore limited. Nevertheless, the potential of applying ceramics at high temperature is very high because of their high melting points and superb oxidation resistance. As ceramics are used at elevated temperature, grain growth may take place at the same time. It can seriously degrade the performance of ceramics. Therefore, the microstructural stability at high temperature for ceramics is essential for high temperature applications.

The presence of a small amount of second phase slows down the coarsening of matrix grains [1]. Recent studies have suggested that the coarsening of 50%Al₂O₃/50%ZrO₂ composite is dramatically slower than that of monolithic ceramics and of composites containing less second phase [2,3]. The potential of duplex composites for elevated temperature applications is therefore worth noting. The mutual solubility between Al₂O₃ and ZrO₂ is limited. The coarsening resistance of the duplex Al₂O₃/ZrO₂ composite has been attributed to the physical constraint (due to the space-filling requirement) [3], the change of coordination number and of dihedral angle [2]. The mutual solubility of Al₂O₃/NiAl₂O₄ system is higher than that of Al₂O₃/ZrO₂ system [4]. For example, the solubility of Al₂O₃ in NiAl₂O₄ increases by 10 mol.% from 1000 to 1700°C. In the present study, the grain growth behavior of duplex Al₂O₃/NiAl₂O₄ composite during sintering is investigated. Furthermore, the process conditions to prepare dense Al₂O₃/NiAl₂O₄ composite are proposed.

2. Experimental

Duplex Al₂O₃/NiAl₂O₄ composites and monolithic NiAl₂O₄ specimens were prepared by reaction sintering Al₂O₃ and NiO powder mixtures [5]. Alpha alumina (TM-DR, Taiimei Chem. Co. Ltd., Tokyo, Japan, particle size = 0.2 µm) and 0.25 and 50 mol.% nickel oxide (Johnson Matthey Co., USA, particle size = 16 µm) were ball milled in alcohol for 4 h with zirconia balls. The slurry was dried with a rotary evaporator. The dried lumps were crushed and passed through a plastic sieve. Powder compacts were first formed by uniaxial pressing at 18 MPa, then by cold isostatic pressing (CIP) at 250 MPa. Sintering was performed in a box furnace at 1500-1700°C in air. Sintering was also performed in a dilatometer (differential dilatometer, Theta Co., USA) that allowed continuous monitoring of the shrinkage kinetics. The heating rate was kept constant as 5°C min⁻¹.

Phases were identified on fired powder compacts by X-ray diffractometry (XRD). The final density was determined by the water displacement method. Before the specimens were submerged in water, a wax was applied to the surface to prevent water penetration. The theoretical densities of composites were calculated from the theoretical density for alumina of 3980 kg m⁻³, for nickel oxide of 6800 kg m⁻³, and for nickel aluminate spinel of 4000 kg m⁻³. The polished
surfaces were prepared by cutting the samples along the axial
direction of the discs and polishing with diamond paste to
6 µm and silica powder to 0.05 µm. The samples were ther-
minally etched at 1550°C for 30 min. The grain size was deter-
mined by the linear intercept technique [6].

3. Results and discussion

The expansion curves for the powder mixtures of Al₂O₃
and NiO are shown in Fig. 1. Owing to the density difference
between Al₂O₃, NiO and NiAl₂O₄, the reaction

\[ \text{Al}_2\text{O}_3 + \text{NiO} = \text{NiAl}_2\text{O}_4 \] (1)

induces a volume expansion. The expansion curves in Fig. 1
indicate that the reaction starts from 1000°C as the powder
mixtures are heated with a heating rate of 5°C min⁻¹. As the
holding time at 1000°C is prolonged, the amount of NiAl₂O₄
can be increased. Fig. 2 shows the XRD pattern for the
Al₂O₃/25%NiO compact after heating at 1000°C for 50 h.
No residual NiO is found within the detection limit of the
instrument (about 1%). It suggests that NiO reacted fully
with Al₂O₃ to form NiAl₂O₄. Since there is 75 mol% Al₂O₃
in the starting powder, residual Al₂O₃ is indicated in Fig. 2.
Therefore, a duplex Al₂O₃/NiAl₂O₄ composite resulted after
the heat treatment. According to the phase diagram [4],
25 mol.% NiO powder mixture results in 55 mol.% NiAl₂O₄,
whereas 50 mol.% NiO powder mixture results in only
NiAl₂O₄ after the heat treatment. To avoid the complexity
induced by the expansion of NiAl₂O₄ formation, all speci-
mens were first heat treated at 1000°C for 50 h.
The density for the heat treated powder compacts is shown
as a function of temperature in Fig. 3. The sintering is carried
out in the dilatometer. Owing to a volume expansion accom-
panied by the formation of NiAl₂O₄, the particles are pushed
apart as the reaction is taken place [7]. A larger pore size
thus results. The density of the specimens is decreased with
the increase of NiAl₂O₄ content. As the heat-treated compacts
are sintered in a box furnace, the relative density is shown as
a function of sintering temperature in Fig. 4. The specimens
are sintered at the indicated temperatures for 5 h. The fired
density is also decreased with the increase of NiAl₂O₄
content.
The grain size of the specimens in Fig. 4 is shown as a
function of temperature in Fig. 5. The grain size of Al₂O₃/
Fig. 5. The grain size of Al₂O₃, Al₂O₃/NiAl₂O₄, NiAl₂O₄ specimens as a function of temperature. The specimens are sintered at the indicated temperatures for 5 h.

Table 1

<table>
<thead>
<tr>
<th>Material</th>
<th>Density (%)</th>
<th>Grain size of Al₂O₃ (µm)</th>
<th>Grain size of NiAl₂O₄ (µm)</th>
</tr>
</thead>
<tbody>
<tr>
<td>Al₂O₃</td>
<td>98.6</td>
<td>15.1</td>
<td>-</td>
</tr>
<tr>
<td>Al₂O₃/NiAl₂O₄</td>
<td>96.6</td>
<td>12.8</td>
<td>9.4</td>
</tr>
<tr>
<td>NiAl₂O₄</td>
<td>97.8</td>
<td>-</td>
<td>16.8</td>
</tr>
</tbody>
</table>

NiAl₂O₄ composite and of NiAl₂O₄ specimen is smaller than that of Al₂O₃. The relative density of the Al₂O₃/NiAl₂O₄ composite is lower than 95%, as the composite sintered at 1675°C for 5 h. A higher sintering temperature, 1700°C, is used to density the composite. The density and grain size of the specimens sintered at 1700°C for 1 h are shown in Table 1. The densities of the specimens in Table 1 are very close to one another. However, the grain size of the composite is the smallest. It thus suggests that the composite is resistant to coarsening at high temperature. Typical microstructures of the specimens are shown in Fig. 6.

The grain growth kinetics can be expressed in terms of the relation

\[ G^n - G_0^n = Kt \]

where \( G \) is the grain size at time \( t \), \( n \) the grain growth kinetic exponent, \( G_0 \) the grain size in the beginning, and \( K \) the grain growth rate constant. When the specimens are sintered at high temperature for 5 h, the grain size \( G \) is much greater than \( G_0 \). Therefore, Eq. (2) can be simplified to

\[ G^n = Kt \]

Grain growth is a thermally activated process. The grain growth rate constant \( K \) is thus a function of temperature \( T \) as

\[ K = K_0 \exp\left(-\frac{Q}{RT}\right) \]

where \( K_0 \) is a constant, \( Q \) the activation energy, and \( R \) the gas constant. The values of \( n \) for ceramics have been suggested to vary from 2 to 4 [8]. The exact value of \( n \) is difficult to be determined with limited data points [9]. A value of \( n = 3 \) was thus chosen to provide a basis for comparison of the values of \( K \). The grain growth rate constant is shown as a function of inverse temperature in Fig. 7. The activation energy for the grain growth is shown in Table 2. The activation energy for Al₂O₃ is slightly lower than the reported value for the diffusion of Al ions along grain boundaries [10]. This may result from the composition difference. The activation energy of Al₂O₃ in the composite is the same as that of monolithic Al₂O₃. However, the activation energy of NiAl₂O₄ in the composite is different from that of monolithic NiAl₂O₄.

For monolithic ceramics, the mass can be transported along the grain boundaries. However, the grain boundaries in a
monolithic microstructure are replaced by the interphase boundaries in a duplex microstructure. Good lattice matching has been observed in the $\text{Al}_2\text{O}_3/\text{NiAl}_2\text{O}_4$ interphase boundary [11]. The structure of the interphase boundary may thus be similar to the structure of the grain boundary of monolithic $\text{Al}_2\text{O}_3$ and of monolithic $\text{NiAl}_2\text{O}_4$. Since the activation energy of $\text{Al}_2\text{O}_3$ in a composite is the same as that of monolithic $\text{Al}_2\text{O}_3$, the grain growth of the composite is likely to be controlled by the diffusion of Al ions along the interphase boundary. From Fig. 6(a), the aspect ratio of $\text{Al}_2\text{O}_3$ grains is slightly higher than unity. However, the $\text{Al}_2\text{O}_3$ grains in the $\text{Al}_2\text{O}_3/\text{NiAl}_2\text{O}_4$ composite are equiaxed instead, Fig. 6(h). The $\text{NiAl}_2\text{O}_4$ grains in $\text{NiAl}_2\text{O}_4$ or in $\text{Al}_2\text{O}_3/\text{NiAl}_2\text{O}_4$ composite are all equiaxed. This suggests that the coarsening of one phase in the composite is constrained by the presence of the other phase and the space filling requirement.

To achieve high density, either the sintering temperature or the sintering time can be increased. The duplex microstructure is resistant to coarsening. Therefore, even if a higher temperature or a longer time is used, the sintering-accompanied coarsening is limited. This can be demonstrated by sintering the specimens at 1700°C, Table 1. A relative density of 97% for the composite is achieved. Furthermore, the grain size of duplex $\text{Al}_2\text{O}_3/\text{NiAl}_2\text{O}_4$ composite is smaller than that of monolithic $\text{Al}_2\text{O}_3$ and $\text{NiAl}_2\text{O}_4$.

4. Conclusions

The grain growth behavior of $\text{Al}_2\text{O}_3$, $\text{Al}_2\text{O}_3/\text{NiAl}_2\text{O}_4$ and $\text{NiAl}_2\text{O}_4$ is studied. Duplex $\text{Al}_2\text{O}_3/\text{NiAl}_2\text{O}_4$ composite is resistant to coarsening at high temperature. The grain growth of duplex $\text{Al}_2\text{O}_3/\text{NiAl}_2\text{O}_4$ composite is controlled by the diffusion of Al ion along the interphase boundary. Because of the space filling requirement, the coarsening of each phase in the composite is constrained. Even though dense duplex $\text{Al}_2\text{O}_3/\text{NiAl}_2\text{O}_4$ composite can only be prepared by sintering at a high temperature, 1700°C. For its coarsening resistance, the microstructure of the composite is still refined. The potential of applying the duplex composite at high temperature is thus high for its microstructural stability.

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References